# **74AUP2G32**

## Low-power dual 2-input OR gate

Rev. 9 — 24 June 2022

**Product data sheet** 

### 1. General description

The 74AUP2G32 is a dual 2-input OR gate. Schmitt-trigger action at all inputs makes the circuit tolerant of slower input rise and fall times. This device ensures very low static and dynamic power consumption across the entire  $V_{CC}$  range from 0.8 V to 3.6 V. This device is fully specified for partial power down applications using  $I_{OFF}$ . The  $I_{OFF}$  circuitry disables the output, preventing the potentially damaging backflow current through the device when it is powered down.

#### 2. Features and benefits

- Wide supply voltage range from 0.8 V to 3.6 V
- · CMOS low power dissipation
- High noise immunity
- Low static power consumption; I<sub>CC</sub> = 0.9 μA (maximum)
- · Latch-up performance exceeds 100 mA per JESD 78 Class II Level B
- Overvoltage tolerant inputs to 3.6 V
- Low noise overshoot and undershoot < 10 % of V<sub>CC</sub>
- I<sub>OFF</sub> circuitry provides partial Power-down mode operation
- · Complies with JEDEC standards:
  - JESD8-12 (0.8 V to 1.3 V)
  - JESD8-11 (0.9 V to 1.65 V)
  - JESD8-7 (1.2 V to 1.95 V)
  - JESD8-5 (1.8 V to 2.7 V)
  - JESD8C (2.7 V to 3.6 V)
- ESD protection:
  - HBM JESD22-A114F Class 3A exceeds 5000 V
  - MM JESD22-A115-A exceeds 200 V
  - CDM JESD22-C101E exceeds 1000 V
- Multiple package options
- Specified from -40 °C to +85 °C and -40 °C to +125 °C



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## 3. Ordering information

**Table 1. Ordering information** 

Type number	Package			
	Temperature range	Name	Description	Version
74AUP2G32DC	-40 °C to +125 °C	VSSOP8	plastic very thin shrink small outline package; 8 leads; body width 2.3 mm	<u>SOT765-1</u>
74AUP2G32GT	-40 °C to +125 °C	XSON8	plastic extremely thin small outline package; no leads; 8 terminals; body 1 × 1.95 × 0.5 mm	SOT833-1
74AUP2G32GF	-40 °C to +125 °C	XSON8	extremely thin small outline package; no leads; 8 terminals; body 1.35 × 1 × 0.5 mm	SOT1089
74AUP2G32GM	-40 °C to +125 °C	XQFN8	plastic, extremely thin quad flat package; no leads; 8 terminals; body 1.6 × 1.6 × 0.5 mm	SOT902-2
74AUP2G32GN	-40 °C to +125 °C	XSON8	extremely thin small outline package; no leads; 8 terminals; body 1.2 × 1.0 × 0.35 mm	<u>SOT1116</u>
74AUP2G32GS	-40 °C to +125 °C	XSON8	extremely thin small outline package; no leads; 8 terminals; body 1.35 × 1.0 × 0.35 mm	SOT1203
74AUP2G32GX	-40 °C to +125 °C	X2SON8	plastic thermal enhanced extremely thin small outline package; no leads; 8 terminals; body 1.35 × 0.8 × 0.32 mm	SOT1233-2

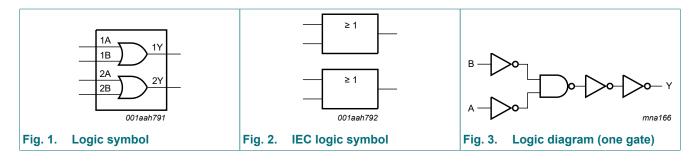
## 4. Marking

Table 2. Marking codes

Table 1: Marking Codes					
Type number	Marking code[1]				
74AUP2G32DC	p32				
74AUP2G32GT	p32				
74AUP2G32GF	pG				
74AUP2G32GM	p32				
74AUP2G32GN	pG				
74AUP2G32GS	pG				
74AUP2G32GX	pG				

<sup>[1]</sup> The pin 1 indicator is located on the lower left corner of the device, below the marking code.

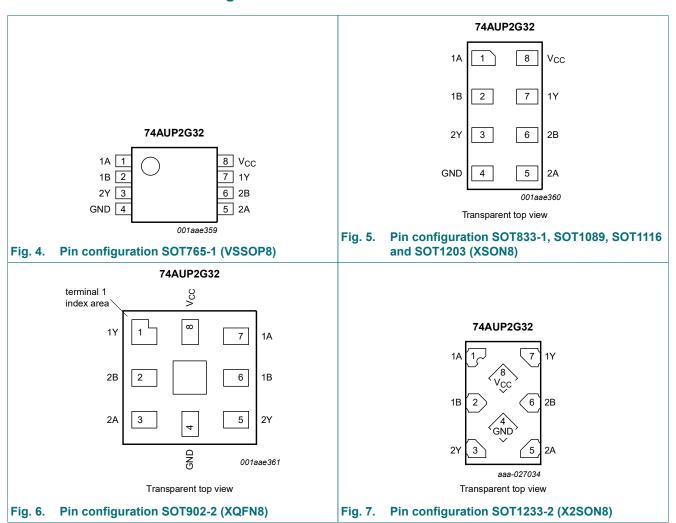
## 5. Functional diagram



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## 6. Pinning information

#### 6.1. Pinning



#### 6.2. Pin description

**Table 3. Pin description** 

Symbol	Pin	Pin			
	SOT765-1, SOT833-1, SOT1089, SOT1116, SOT1203 and SOT1233-2	SOT902-2			
1A, 2A	1, 5	7, 3	data input		
1B, 2B	2, 6	6, 2	data input		
GND	4	4	ground (0 V)		
1Y, 2Y	7, 3	1, 5	data output		
V <sub>CC</sub>	8	8	supply voltage		

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### 7. Functional description

#### **Table 4. Function table**

 $H = HIGH \ voltage \ level; \ L = LOW \ voltage \ level.$ 

Input	Output	
nA	nB	nY
L	L	L
L	Н	Н
Н	L	Н
Н	Н	Н

### 8. Limiting values

#### **Table 5. Limiting values**

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		Min	Max	Unit
V <sub>CC</sub>	supply voltage			-0.5	+4.6	V
VI	input voltage		[1]	-0.5	+4.6	V
Vo	output voltage	Active mode and Power-down mode	[1]	-0.5	+4.6	V
I <sub>IK</sub>	input clamping current	V <sub>I</sub> < 0 V		-50	-	mA
I <sub>OK</sub>	output clamping current	V <sub>O</sub> < 0 V		-50	-	mA
Io	output current	$V_O = 0 V \text{ to } V_{CC}$		-	±20	mA
I <sub>CC</sub>	supply current			-	+50	mA
I <sub>GND</sub>	ground current			-50	-	mA
T <sub>stg</sub>	storage temperature			-65	+150	°C
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> = -40 °C to +125 °C				
		SOT765-1 (VSSOP8) SOT833-1 (XSON8) SOT1089 (XSON8) SOT902-2 (XQFN8) SOT1116 (XSON8) SOT1203 (XSON8) SOT1233-2 (X2SON8)	[2] [3] [4] [5] [6] [7]	- - - - -	250 250 250 250 250 250 250 300	mW mW mW mW mW

- [1] The minimum input and output voltage ratings may be exceeded if the input and output current ratings are observed.
- 2] For SOT765-1 (VSSOP8) package: Ptot derates linearly with 4.9 mW/K above 99 °C.
- 3] For SOT833-1 (XSON8) package: P<sub>tot</sub> derates linearly with 3.1 mW/K above 68 °C.
- [4] For SOT1089 (XSON8) package: P<sub>tot</sub> derates linearly with 4.0 mW/K above 88 °C.
- [5] For SOT902-2 (XQFN8) packages: P<sub>tot</sub> derates linearly with 4.1 mW/K above 89 °C.
- [6] For SOT1116 (XSON8) package: P<sub>tot</sub> derates linearly with 4.2 mW/K above 90 °C.
- [7] For SOT1203 (XSON8) package: P<sub>tot</sub> derates linearly with 3.6 mW/K above 81 °C.
- [8] For SOT1233-2 (X2SON8) package: P<sub>tot</sub> derates linearly with 7.7 mW/K above 118 °C.

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## 9. Recommended operating conditions

#### **Table 6. Operating conditions**

Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>CC</sub>	supply voltage		0.8	3.6	V
VI	input voltage		0	3.6	V
Vo	output voltage	Active mode	0	V <sub>CC</sub>	V
		Power-down mode; V <sub>CC</sub> = 0 V	0	3.6	V
T <sub>amb</sub>	ambient temperature		-40	+125	°C
Δt/ΔV	input transition rise and fall rate	V <sub>CC</sub> = 0.8 V to 3.6 V	0	200	ns/V

### 10. Static characteristics

#### **Table 7. Static characteristics**

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T <sub>amb</sub> = 2	5 °C					•
V <sub>IH</sub>	HIGH-level input voltage	V <sub>CC</sub> = 0.8 V	0.70 × V <sub>CC</sub>	-	-	V
		V <sub>CC</sub> = 0.9 V to 1.95 V	0.65 × V <sub>CC</sub>	-	-	V
		V <sub>CC</sub> = 2.3 V to 2.7 V	1.6	-	-	V
		V <sub>CC</sub> = 3.0 V to 3.6 V	2.0	-	-	V
V <sub>IL</sub>	LOW-level input voltage	V <sub>CC</sub> = 0.8 V	-	-	0.30 × V <sub>CC</sub>	V
		V <sub>CC</sub> = 0.9 V to 1.95 V	-	-	0.35 × V <sub>CC</sub>	V
		V <sub>CC</sub> = 2.3 V to 2.7 V	-	-	0.7	V
		V <sub>CC</sub> = 3.0 V to 3.6 V	-	-	0.9	V
V <sub>OH</sub>	HIGH-level output voltage	$V_I = V_{IH}$ or $V_{IL}$				
		$I_{O}$ = -20 $\mu$ A; $V_{CC}$ = 0.8 $V$ to 3.6 $V$	V <sub>CC</sub> - 0.1	-	-	V
		I <sub>O</sub> = -1.1 mA; V <sub>CC</sub> = 1.1 V	0.75 × V <sub>CC</sub>	-	-	V
		I <sub>O</sub> = -1.7 mA; V <sub>CC</sub> = 1.4 V	1.11	-	-	V
		I <sub>O</sub> = -1.9 mA; V <sub>CC</sub> = 1.65 V	1.32	-	-	V
		I <sub>O</sub> = -2.3 mA; V <sub>CC</sub> = 2.3 V	2.05	-	-	V
		I <sub>O</sub> = -3.1 mA; V <sub>CC</sub> = 2.3 V	1.9	-	-	V
		$I_{O}$ = -2.7 mA; $V_{CC}$ = 3.0 V	2.72	-	-	V
		I <sub>O</sub> = -4.0 mA; V <sub>CC</sub> = 3.0 V	2.6	-	-	V
V <sub>OL</sub>	LOW-level output voltage	$V_I = V_{IH}$ or $V_{IL}$				
		$I_{O}$ = 20 $\mu$ A; $V_{CC}$ = 0.8 V to 3.6 V	-	-	0.1	V
		I <sub>O</sub> = 1.1 mA; V <sub>CC</sub> = 1.1 V	-	-	0.3 × V <sub>CC</sub>	V
		I <sub>O</sub> = 1.7 mA; V <sub>CC</sub> = 1.4 V	-	-	0.31	V
		I <sub>O</sub> = 1.9 mA; V <sub>CC</sub> = 1.65 V	-	-	0.31	V
		$I_O = 2.3 \text{ mA}; V_{CC} = 2.3 \text{ V}$	-	-	0.31	V
		I <sub>O</sub> = 3.1 mA; V <sub>CC</sub> = 2.3 V	-	-	0.44	V
		I <sub>O</sub> = 2.7 mA; V <sub>CC</sub> = 3.0 V	-	-	0.31	V
		I <sub>O</sub> = 4.0 mA; V <sub>CC</sub> = 3.0 V	-	-	0.44	V
l <sub>l</sub>	input leakage current	$V_{I}$ = GND to 3.6 V; $V_{CC}$ = 0 V to 3.6 V	-	-	±0.1	μΑ
I <sub>OFF</sub>	power-off leakage current	$V_{I}$ or $V_{O}$ = 0 V to 3.6 V; $V_{CC}$ = 0 V	-	-	±0.2	μΑ

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Δl <sub>OFF</sub>	additional power-off leakage current	V <sub>I</sub> or V <sub>O</sub> = 0 V to 3.6 V; V <sub>CC</sub> = 0 V to 0.2 V	-	-	±0.2	μΑ
I <sub>CC</sub>	supply current	$V_I = GND \text{ or } V_{CC}; I_O = 0 \text{ A};$ $V_{CC} = 0.8 \text{ V to } 3.6 \text{ V}$	-	-	0.5	μΑ
Δl <sub>CC</sub>	additional supply current	$V_1 = V_{CC} - 0.6 \text{ V}; I_O = 0 \text{ A};$ [1] $V_{CC} = 3.3 \text{ V}$	-	-	40	μA
Cı	input capacitance	$V_{CC}$ = 0 V to 3.6 V; $V_I$ = GND or $V_{CC}$	-	0.6	-	pF
Co	output capacitance	$V_O = GND; V_{CC} = 0 V$	-	1.3	-	pF
T <sub>amb</sub> = -	40 °C to +85 °C					
V <sub>IH</sub>	HIGH-level input voltage	V <sub>CC</sub> = 0.8 V	0.70 × V <sub>CC</sub>	-	-	V
		V <sub>CC</sub> = 0.9 V to 1.95 V	0.65 × V <sub>CC</sub>	-	-	V
		V <sub>CC</sub> = 2.3 V to 2.7 V	1.6	-	-	V
		V <sub>CC</sub> = 3.0 V to 3.6 V	2.0	-	-	V
V <sub>IL</sub>	LOW-level input voltage	V <sub>CC</sub> = 0.8 V	-	-	0.30 × V <sub>CC</sub>	V
		V <sub>CC</sub> = 0.9 V to 1.95 V	-	-	0.35 × V <sub>CC</sub>	V
		V <sub>CC</sub> = 2.3 V to 2.7 V	-	-	0.7	V
		V <sub>CC</sub> = 3.0 V to 3.6 V	-	-	0.9	V
V <sub>OH</sub>	HIGH-level output voltage	$V_I = V_{IH}$ or $V_{IL}$				
		I <sub>O</sub> = -20 μA; V <sub>CC</sub> = 0.8 V to 3.6 V	V <sub>CC</sub> - 0.1	-	-	V
		I <sub>O</sub> = -1.1 mA; V <sub>CC</sub> = 1.1 V	0.7 × V <sub>CC</sub>	-	-	V
		I <sub>O</sub> = -1.7 mA; V <sub>CC</sub> = 1.4 V	1.03	-	-	V
		I <sub>O</sub> = -1.9 mA; V <sub>CC</sub> = 1.65 V	1.30	-	-	V
		$I_{O}$ = -2.3 mA; $V_{CC}$ = 2.3 V	1.97	-	-	V
		I <sub>O</sub> = -3.1 mA; V <sub>CC</sub> = 2.3 V	1.85	-	-	V
		$I_O = -2.7 \text{ mA}; V_{CC} = 3.0 \text{ V}$	2.67	-	-	V
		$I_O = -4.0 \text{ mA}$ ; $V_{CC} = 3.0 \text{ V}$	2.55	-	-	V
V <sub>OL</sub>	LOW-level output voltage	$V_I = V_{IH}$ or $V_{IL}$				
		$I_O = 20 \mu A$ ; $V_{CC} = 0.8 \text{ V to } 3.6 \text{ V}$	-	-	0.1	V
		I <sub>O</sub> = 1.1 mA; V <sub>CC</sub> = 1.1 V	-	-	0.3 × V <sub>CC</sub>	V
		I <sub>O</sub> = 1.7 mA; V <sub>CC</sub> = 1.4 V	-	-	0.37	V
		I <sub>O</sub> = 1.9 mA; V <sub>CC</sub> = 1.65 V	-	-	0.35	V
		I <sub>O</sub> = 2.3 mA; V <sub>CC</sub> = 2.3 V	-	-	0.33	V
		I <sub>O</sub> = 3.1 mA; V <sub>CC</sub> = 2.3 V	-	_	0.45	V
		I <sub>O</sub> = 2.7 mA; V <sub>CC</sub> = 3.0 V	-	-	0.33	V
		I <sub>O</sub> = 4.0 mA; V <sub>CC</sub> = 3.0 V	-	_	0.45	V
I <sub>I</sub>	input leakage current	$V_1 = GND \text{ to } 3.6 \text{ V}; V_{CC} = 0 \text{ V to } 3.6 \text{ V}$	-	_	±0.5	μA
l <sub>OFF</sub>	power-off leakage current	$V_1$ or $V_0 = 0$ V to 3.6 V; $V_{CC} = 0$ V	-	_	±0.5	μA
Δl <sub>OFF</sub>	additional power-off leakage current	V <sub>I</sub> or V <sub>O</sub> = 0 V to 3.6 V; V <sub>CC</sub> = 0 V to 0.2 V	-	-	±0.6	μΑ
I <sub>CC</sub>	supply current	V <sub>I</sub> = GND or V <sub>CC</sub> ; I <sub>O</sub> = 0 A; V <sub>CC</sub> = 0.8 V to 3.6 V	-	-	0.9	μA
ΔI <sub>CC</sub>	additional supply current	$V_1 = V_{CC} - 0.6 \text{ V}; I_O = 0 \text{ A};$ [1] $V_{CC} = 3.3 \text{ V}$	-	-	50	μA

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T <sub>amb</sub> = -4	40 °C to +125 °C					
V <sub>IH</sub>	HIGH-level input voltage	V <sub>CC</sub> = 0.8 V	0.75 × V <sub>CC</sub>	-	-	V
		V <sub>CC</sub> = 0.9 V to 1.95 V	0.70 × V <sub>CC</sub>	-	-	V
		V <sub>CC</sub> = 2.3 V to 2.7 V	1.6	-	-	V
		V <sub>CC</sub> = 3.0 V to 3.6 V	2.0	-	-	V
V <sub>IL</sub>	LOW-level input voltage	V <sub>CC</sub> = 0.8 V	-	-	0.25 × V <sub>CC</sub>	V
		V <sub>CC</sub> = 0.9 V to 1.95 V	-	-	0.30 × V <sub>CC</sub>	V
		V <sub>CC</sub> = 2.3 V to 2.7 V	-	-	0.7	V
		V <sub>CC</sub> = 3.0 V to 3.6 V	-	-	0.9	V
V <sub>OH</sub>	HIGH-level output voltage	$V_I = V_{IH}$ or $V_{IL}$				
		$I_O = -20 \mu A$ ; $V_{CC} = 0.8 \text{ V to } 3.6 \text{ V}$	V <sub>CC</sub> - 0.11	-	-	V
		I <sub>O</sub> = -1.1 mA; V <sub>CC</sub> = 1.1 V	0.6 × V <sub>CC</sub>	-	-	V
		I <sub>O</sub> = -1.7 mA; V <sub>CC</sub> = 1.4 V	0.93	-	-	V
		I <sub>O</sub> = -1.9 mA; V <sub>CC</sub> = 1.65 V	1.17	-	-	V
		$I_{O}$ = -2.3 mA; $V_{CC}$ = 2.3 V	1.77	-	-	V
		$I_O = -3.1 \text{ mA}; V_{CC} = 2.3 \text{ V}$	1.67	-	-	V
		$I_{O}$ = -2.7 mA; $V_{CC}$ = 3.0 V	2.40	-	-	V
		$I_{O}$ = -4.0 mA; $V_{CC}$ = 3.0 V	2.30	-	-	V
V <sub>OL</sub>	LOW-level output voltage	$V_I = V_{IH}$ or $V_{IL}$				
		$I_O = 20 \mu A; V_{CC} = 0.8 \text{ V to } 3.6 \text{ V}$	-	-	0.11	V
		I <sub>O</sub> = 1.1 mA; V <sub>CC</sub> = 1.1 V	-	-	0.33 × V <sub>CC</sub>	V
		I <sub>O</sub> = 1.7 mA; V <sub>CC</sub> = 1.4 V	-	-	0.41	V
		I <sub>O</sub> = 1.9 mA; V <sub>CC</sub> = 1.65 V	-	-	0.39	V
		$I_{O}$ = 2.3 mA; $V_{CC}$ = 2.3 V	-	-	0.36	V
		$I_O = 3.1 \text{ mA}; V_{CC} = 2.3 \text{ V}$	-	-	0.50	V
		I <sub>O</sub> = 2.7 mA; V <sub>CC</sub> = 3.0 V	-	-	0.36	V
		I <sub>O</sub> = 4.0 mA; V <sub>CC</sub> = 3.0 V	-	-	0.50	V
l <sub>l</sub>	input leakage current	$V_I = GND \text{ to } 3.6 \text{ V}; V_{CC} = 0 \text{ V to } 3.6 \text{ V}$	-	-	±0.75	μΑ
l <sub>OFF</sub>	power-off leakage current	$V_I$ or $V_O = 0$ V to 3.6 V; $V_{CC} = 0$ V	-	-	±0.75	μΑ
Δl <sub>OFF</sub>	additional power-off leakage current	V <sub>I</sub> or V <sub>O</sub> = 0 V to 3.6 V; V <sub>CC</sub> = 0 V to 0.2 V	-	-	±0.75	μΑ
I <sub>CC</sub>	supply current	$V_{I}$ = GND or $V_{CC}$ ; $I_{O}$ = 0 A; $V_{CC}$ = 0.8 V to 3.6 V	-	-	1.4	μΑ
Δl <sub>CC</sub>	additional supply current	$V_1 = V_{CC} - 0.6 \text{ V}; I_O = 0 \text{ A};$ [1] $V_{CC} = 3.3 \text{ V}$	-	-	75	μΑ

<sup>[1]</sup> One input at  $V_{CC}$  - 0.6 V, other input at  $V_{CC}$  or GND.

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## 11. Dynamic characteristics

#### **Table 8. Dynamic characteristics**

Voltages are referenced to GND (ground = 0 V); for test circuit see Fig. 9.

Symbol	Parameter	Conditions	T,	<sub>amb</sub> = 25 °	C.	T <sub>an</sub>	<sub>nb</sub> = o +85 °C	T <sub>an</sub> -40 °C to	<sub>nb</sub> = 0 +125 °C	Unit
			Min	Typ[1]	Max	Min	Max	Min	Max	
C <sub>L</sub> = 5 p	F									
t <sub>pd</sub>	propagation	nA or nB to nY; see Fig. 8 [2]								
	delay	V <sub>CC</sub> = 0.8 V	-	16.8	-	-	-	-	-	ns
		V <sub>CC</sub> = 1.1 V to 1.3 V	2.4	5.1	10.9	2.1	11.9	2.1	13.2	ns
		V <sub>CC</sub> = 1.4 V to 1.6 V	1.6	3.6	6.6	1.4	7.5	1.4	8.3	ns
		V <sub>CC</sub> = 1.65 V to 1.95 V	1.4	3.0	5.2	1.2	6.0	1.2	6.6	ns
		V <sub>CC</sub> = 2.3 V to 2.7 V	1.1	2.4	3.9	1.0	4.6	1.0	5.1	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	1.0	2.1	3.5	0.9	4.1	0.9	4.6	ns
C <sub>L</sub> = 10	pF									
t <sub>pd</sub>	propagation	nA or nB to nY; see Fig. 8 [2]								
	delay	V <sub>CC</sub> = 0.8 V	-	20.3	-	-	-	-	-	ns
		V <sub>CC</sub> = 1.1 V to 1.3 V	2.3	5.9	12.7	2.1	13.8	2.1	15.2	ns
		V <sub>CC</sub> = 1.4 V to 1.6 V	1.9	4.2	7.7	1.7	8.7	1.7	9.6	ns
		V <sub>CC</sub> = 1.65 V to 1.95 V	1.7	3.5	6.0	1.5	6.9	1.5	7.7	ns
		V <sub>CC</sub> = 2.3 V to 2.7 V	1.4	2.9	4.6	1.3	5.5	1.3	6.1	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	1.3	2.7	4.3	1.2	5.0	1.2	5.5	ns
C <sub>L</sub> = 15	pF									
t <sub>pd</sub>	propagation	nA or nB to nY; see Fig. 8 [2]								
	delay	V <sub>CC</sub> = 0.8 V	-	23.8	-	-	-	-	-	ns
		V <sub>CC</sub> = 1.1 V to 1.3 V	3.3	6.7	14.3	3.0	15.6	3.0	17.2	ns
		V <sub>CC</sub> = 1.4 V to 1.6 V	2.3	4.8	8.6	2.0	9.8	2.0	10.8	ns
		V <sub>CC</sub> = 1.65 V to 1.95 V	2.0	4.0	6.7	1.8	7.9	1.8	8.7	ns
		V <sub>CC</sub> = 2.3 V to 2.7 V	1.7	3.3	5.3	1.6	6.3	1.6	6.9	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	1.5	3.1	4.9	1.5	5.8	1.5	6.4	ns
C <sub>L</sub> = 30	pF									
t <sub>pd</sub>	propagation	nA or nB to nY; see Fig. 8 [2]								
	delay	V <sub>CC</sub> = 0.8 V	-	34.1	-	-	-	-	-	ns
		V <sub>CC</sub> = 1.1 V to 1.3 V	4.5	9.0	19.1	4.0	21.5	4.0	23.7	ns
		V <sub>CC</sub> = 1.4 V to 1.6 V	3.4	6.3	11.3	2.9	13.3	2.9	14.7	ns
		V <sub>CC</sub> = 1.65 V to 1.95 V	2.6	5.3	8.9	2.4	10.7	2.4	11.8	ns
		V <sub>CC</sub> = 2.3 V to 2.7 V	2.3	4.4	7.0	2.2	8.4	2.2	9.3	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	2.2	4.2	6.4	2.1	7.7	2.1	8.5	ns

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Symbol	Parameter	Conditions	T <sub>amb</sub> = 25 °C		T <sub>an</sub> -40 °C to	<sub>nb</sub> = 0 +125 °C	Unit			
			Min	Typ[1]	Max	Min	Max	Min	Max	
C <sub>L</sub> = 5 p	F, 10 pF, 15 p	F and 30 pF								
C <sub>PD</sub>	power dissipation	$f_i$ = 1 MHz; [3] $V_I$ = GND to $V_{CC}$								
	capacitance	V <sub>CC</sub> = 0.8 V	-	2.6	-	-	-	-	-	pF
		V <sub>CC</sub> = 1.1 V to 1.3 V	-	2.7	-	-	-	-	-	pF
		V <sub>CC</sub> = 1.4 V to 1.6 V	-	2.7	-	-	-	-	-	pF
		V <sub>CC</sub> = 1.65 V to 1.95 V	-	2.9	-	-	-	-	-	pF
		V <sub>CC</sub> = 2.3 V to 2.7 V	-	3.3	-	-	-	-	-	pF
		V <sub>CC</sub> = 3.0 V to 3.6 V	-	3.7	-	-	-	-	-	pF

- All typical values are measured at nominal V<sub>CC</sub>.
- $t_{pd}$  is the same as  $t_{PLH}$  and  $t_{PHL}$ .  $C_{PD}$  is used to determine the dynamic power dissipation ( $P_D$  in  $\mu W$ ).

$$P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma (C_L \times V_{CC}^2 \times f_o)$$
 where:

 $f_i$  = input frequency in MHz;

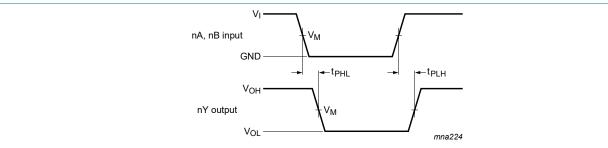
fo = output frequency in MHz;

C<sub>L</sub> = output load capacitance in pF;

V<sub>CC</sub> = supply voltage in V;

N = number of inputs switching;  $\Sigma (C_L \times V_{CC}^2 \times f_0) = \text{sum of the outputs.}$ 

#### 11.1. Waveform and test circuit



Measurement points are given in Table 9.

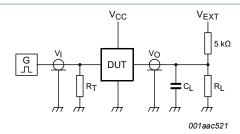
Logic levels: V<sub>OL</sub> and V<sub>OH</sub> are typical output voltage levels that occur with the output load.

The data input (nA or nB) to output (nY) propagation delays

**Table 9. Measurement points** 

Supply voltage	Output						
V <sub>CC</sub>	V <sub>M</sub>	$V_{\rm M}$ $V_{\rm I}$ $t_{\rm r}=t_{\rm f}$					
0.8 V to 3.6 V	0.5 × V <sub>CC</sub>	V <sub>CC</sub>	≤ 3.0 ns	0.5 × V <sub>CC</sub>			

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Test data is given in Table 10.

Definitions for test circuit:

R<sub>L</sub> = Load resistance;

C<sub>L</sub> = Load capacitance including jig and probe capacitance;

 $R_T$  = Termination resistance should be equal to the output impedance  $Z_o$  of the pulse generator;

 $V_{\text{EXT}}$  = External voltage for measuring switching times.

#### Fig. 9. Test circuit for measuring switching times

#### Table 10. Test data

Supply voltage	Load		V <sub>EXT</sub>		
V <sub>CC</sub>	CL	R <sub>L</sub> [1]	t <sub>PLH</sub> , t <sub>PHL</sub>	t <sub>PZH</sub> , t <sub>PHZ</sub>	t <sub>PZL</sub> , t <sub>PLZ</sub>
0.8 V to 3.6 V	5 pF, 10 pF, 15 pF and 30 pF	5 kΩ or 1 MΩ	open	GND	2 × V <sub>CC</sub>

[1] For measuring enable and disable times  $R_L$  = 5 k $\Omega$ . For measuring propagation delays, setup and hold times and pulse width  $R_L$  = 1 M $\Omega$ .

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## 12. Package outline

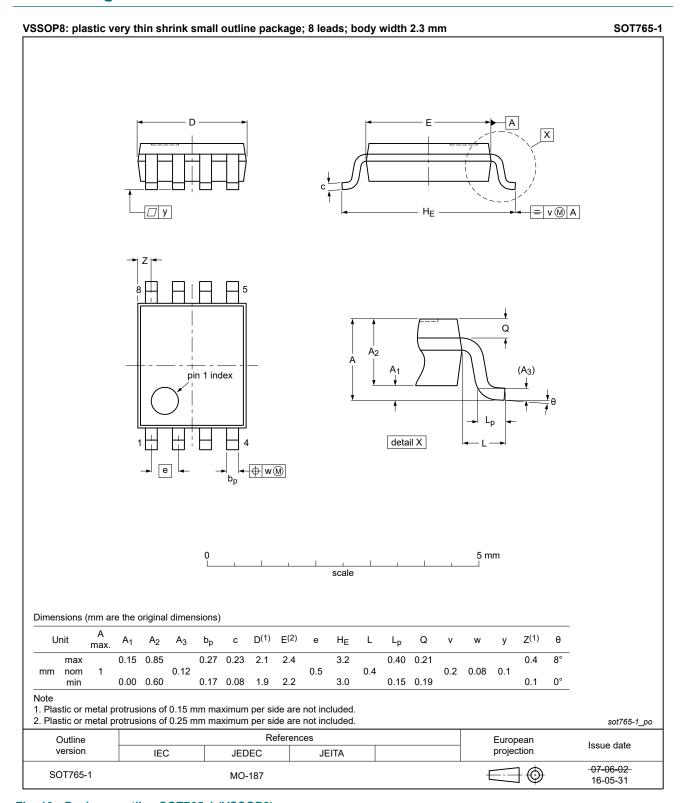


Fig. 10. Package outline SOT765-1 (VSSOP8)

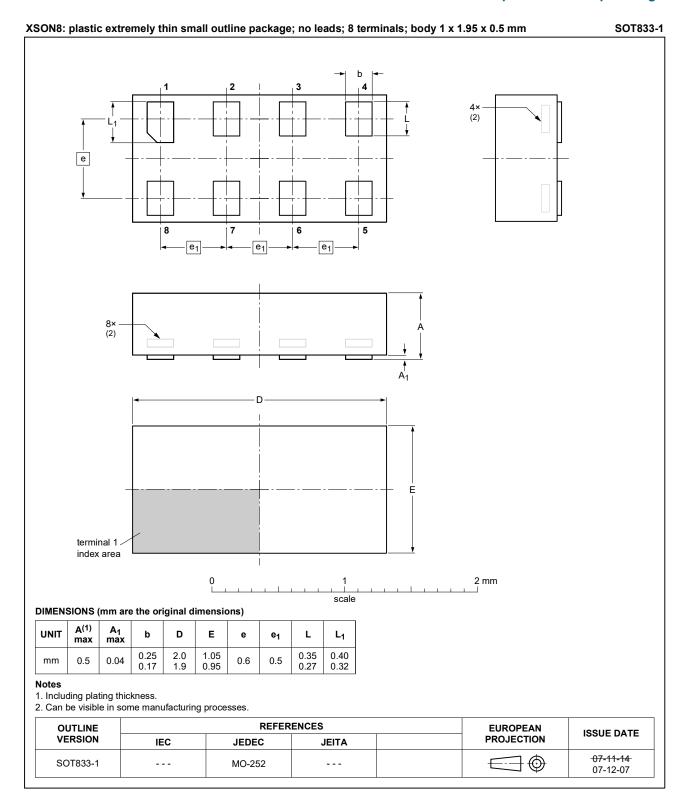


Fig. 11. Package outline SOT833-1 (XSON8)

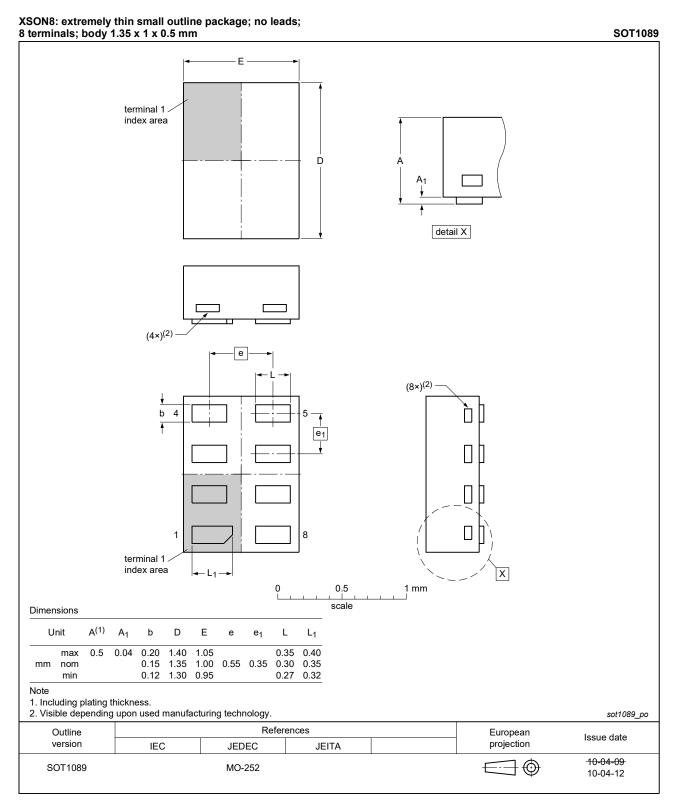


Fig. 12. Package outline SOT1089 (XSON8)

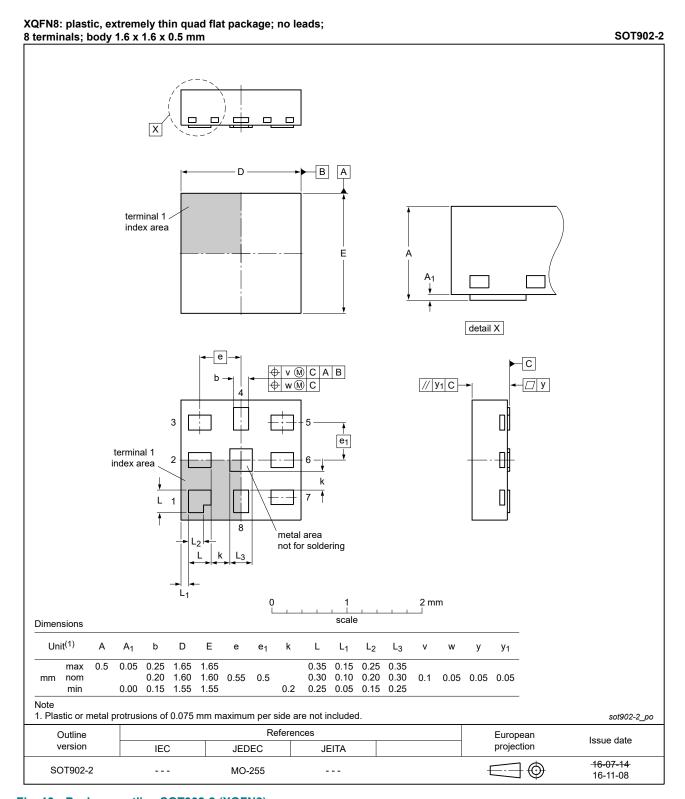


Fig. 13. Package outline SOT902-2 (XQFN8)

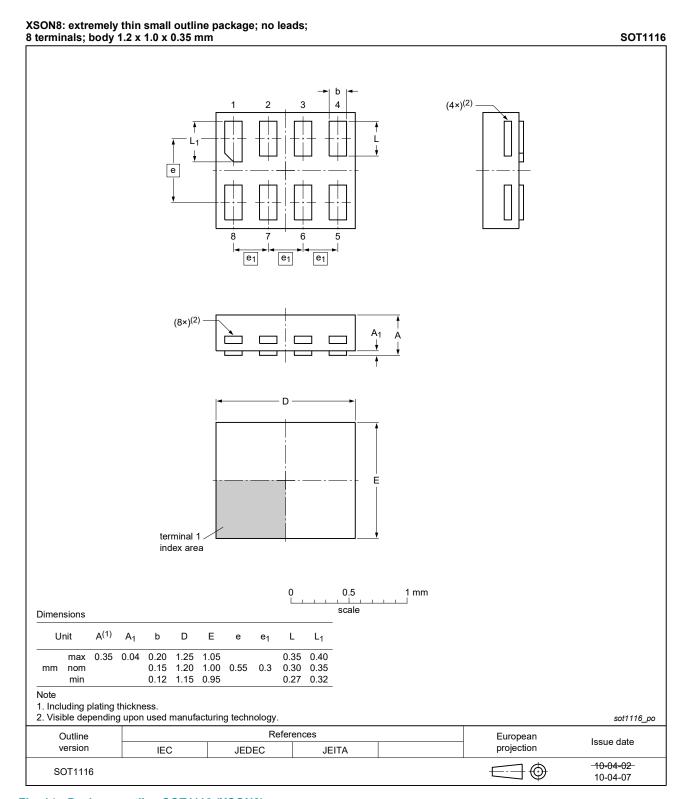


Fig. 14. Package outline SOT1116 (XSON8)

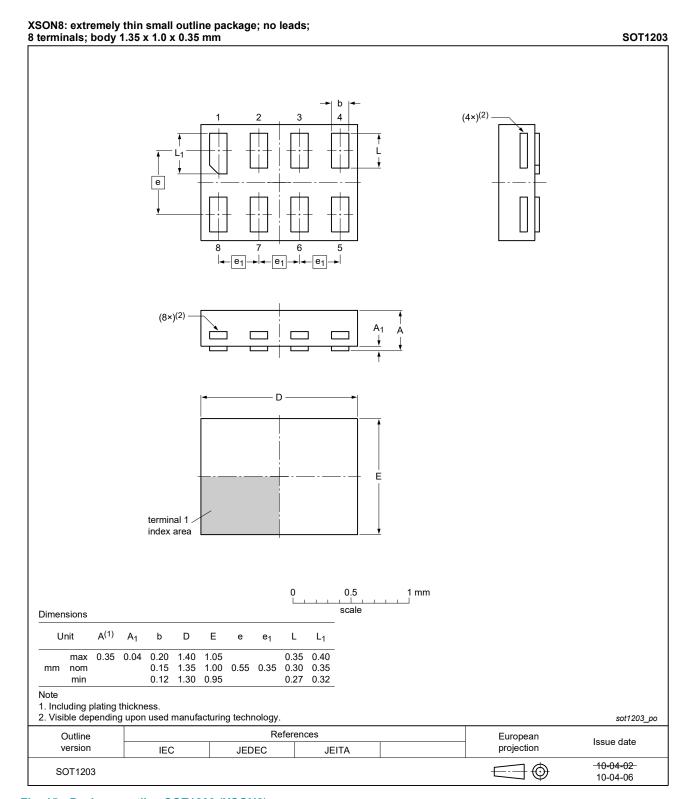


Fig. 15. Package outline SOT1203 (XSON8)

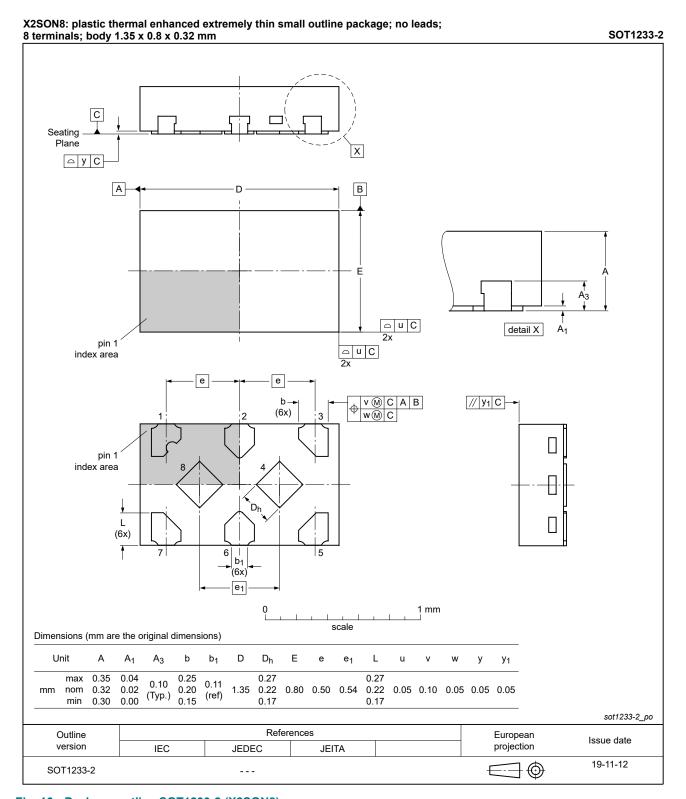


Fig. 16. Package outline SOT1233-2 (X2SON8)

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## 13. Abbreviations

#### **Table 11. Abbreviations**

Acronym	Description
CDM	Charged Device Model
DUT	Device Under Test
ESD	ElectroStatic Discharge
НВМ	Human Body Model
MM	Machine Model

## 14. Revision history

#### **Table 12. Revision history**

Document ID	Release date	Data sheet status	Change notice	Supersedes	
74AUP2G32 v.9	20220624	Product data sheet	-	74AUP2G32 v.8	
Modifications:	<ul> <li>SOT1233 (X2SON8) package changed to SOT1233-2 (X2SON8) package.</li> <li>Section 1 and Section 2 updated.</li> <li>Table 5: Derating values for P<sub>tot</sub> total power dissipation have been updated.</li> </ul>				
74AUP2G32 v.8	20170703	Product data sheet	-	74AUP2G32 v.7	
Modifications:	<ul> <li>The format of this data sheet has been redesigned to comply with the identity guidelines of Nexperia.</li> <li>Legal texts have been adapted to the new company name where appropriate.</li> <li>Type number 74AUP2G32GX (SOT1233 / X2SON8) added.</li> <li>Type number 74AUP2G32GD removed.</li> </ul>				
74AUP2G32 v.7	20130123	Product data sheet	-	74AUP2G32 v.6	
74AUP2G32 v.7 Modifications:		Product data sheet mber 74AUP2G32GD XSO	- N8U has changed		
			- N8U has changed		
Modifications:	For type nur	mber 74AUP2G32GD XSO	- N8U has changed - -	d to XSON8.	
Modifications: 74AUP2G32 v.6	• For type nur 20120605	mber 74AUP2G32GD XSC	- N8U has changed - -	d to XSON8. 74AUP2G32 v.5	
Modifications: 74AUP2G32 v.6 74AUP2G32 v.5	• For type nur 20120605 20111206	mber 74AUP2G32GD XSO Product data sheet Product data sheet	- N8U has changed - - -	to XSON8. 74AUP2G32 v.5 74AUP2G32 v.4	
Modifications: 74AUP2G32 v.6 74AUP2G32 v.5 74AUP2G32 v.4	• For type nur 20120605 20111206 20101021	mber 74AUP2G32GD XSC Product data sheet Product data sheet Product data sheet	- N8U has changed - - - -	to XSON8.  74AUP2G32 v.5  74AUP2G32 v.4  74AUP2G32 v.3	

#### Low-power dual 2-input OR gate

### 15. Legal information

#### **Data sheet status**

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
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### Low-power dual 2-input OR gate

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